



DESCRIPTION

The MMBT3904L is available in SOT-23 package.

FEATURE

- High Voltage Transistors
- Complementary to MMBT3906L
- Available in SOT-23 Package

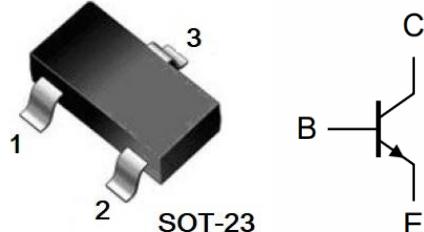
ORDERING INFORMATION

Package Type	Part Number
SOT-23	MMBT3904L
Note	SPQ: 3,000pcs/Reel
AiT provides all RoHS Compliant Products	

HFE CLASSIFICATION

Classification	hFE
MMBT3904L	100~300

PIN DESCRIPTION



PIN#	DESCRIPTION
1	BASE
2	EMITTER
3	COLLECTOR

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

V_{CBO} , Collector-Base Voltage	60V
V_{CEO} , Collector-Emitter Voltage	40V
V_{EBO} , Emitter-Base Voltage	6V
I_c , Collector Current-Continuous	200mA
P_c , Collector Power Dissipation	200mW
T_J , Junction Temperature Range	150°C
T_{STG} , Storage Temperature Range	-55°C~+150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Collector-Base Breakdown Voltage	V_{CBO}	$I_C = 100\mu\text{A}, I_E = 0$	60	-	-	V
Collector-Emitter Breakdown Voltage	V_{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	40	-	-	V
Emitter-Base Breakdown Voltage	V_{EBO}	$I_E = 100\mu\text{A}, I_C = 0$	6	-	-	V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = 60\text{V}, I_E = 0$	-	-	100	nA
Collector-Emitter Cut-Off Current	I_{CEX}	$V_{CE} = 30\text{V}, V_{EB(\text{off})} = -3\text{V}$	-	-	50	
Emitter Cut-Off Current	I_{EBO}	$V_{EB} = 5\text{V}, I_C = 0$	-	-	100	nA
DC Current Gain*	h_{FE}	$V_{CE} = 1\text{V}, I_C = 10\text{mA}$	100	-	400	-
		$V_{CE} = 1\text{V}, I_C = 50\text{mA}$	60	-	-	
		$V_{CE} = 1\text{V}, I_C = 100\text{mA}$	30	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	-	-	0.20	V
		$I_C = 50\text{mA}, I_B = 5\text{mA}$			0.30	
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	0.65	-	0.85	V
		$I_C = 50\text{mA}, I_B = 5\text{mA}$			0.95	
Transition Frequency	f_T	$V_{CE} = 20\text{V}, I_C = 10\text{mA}, f = 100\text{MHz}$	300	-	-	MHz
Collector input capacitance	C_{ib}	$V_{EB} = 0.5\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	8	pF
Collector output capacitance	C_{ob}	$V_{CB} = 5\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	4	MHz
Delay time	t_d	$V_{CC} = 3\text{V}, V_{BE(\text{off})} = -0.5\text{V}$			35	ns
Rise time	t_r				35	
Storage time	t_s	$V_{CC} = 3\text{V}, I_C = 10\text{mA}$			200	
Fall time	t_f				50	



TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. Static Characteristic

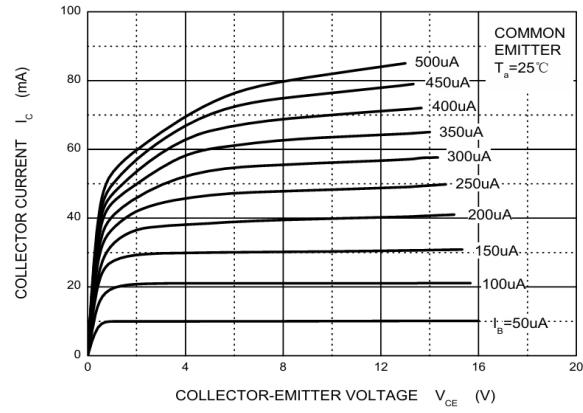


Fig 2. h_{FE} vs. I_c

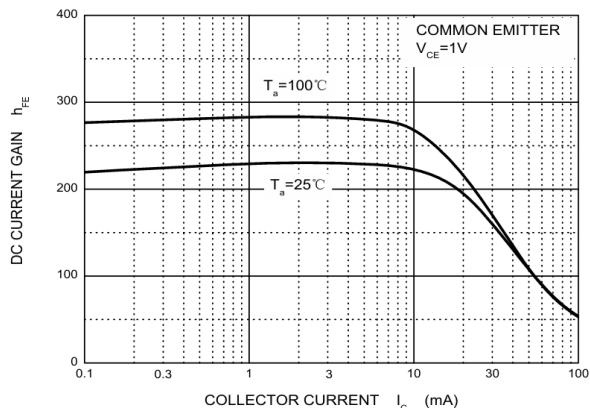


Fig 3. $V_{CE(\text{sat})}$ vs. I_c

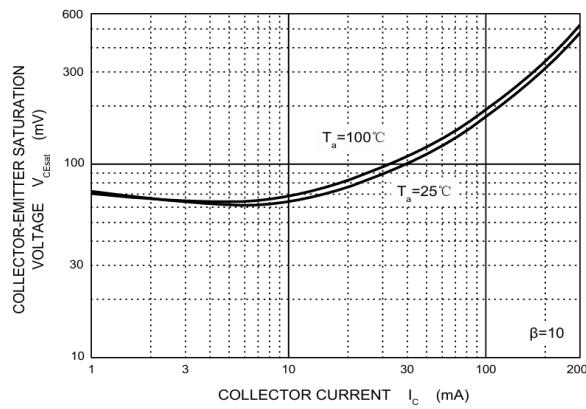


Fig 4. $V_{BE(\text{sat})}$ vs. I_c

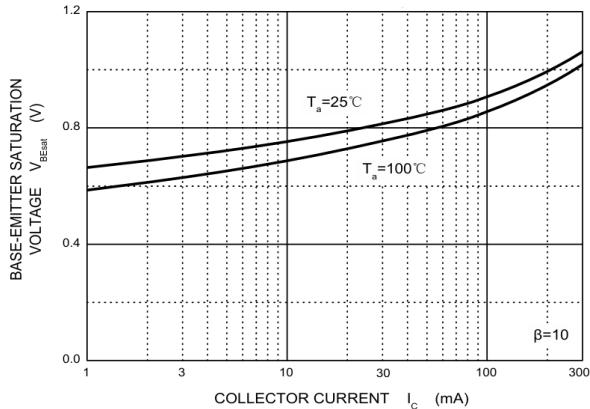


Fig 5. V_{BE} vs. I_c

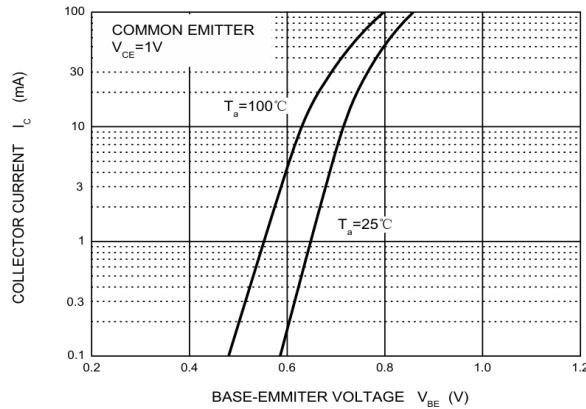
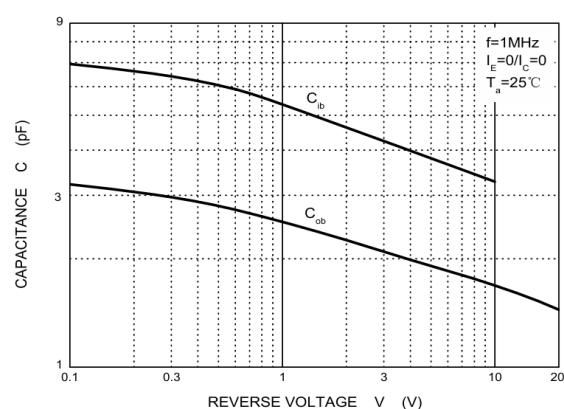


Fig 6. C_{ob} / C_{ib} vs. V_{CB} / V_{EB}





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Fig 7. f_T vs. I_C

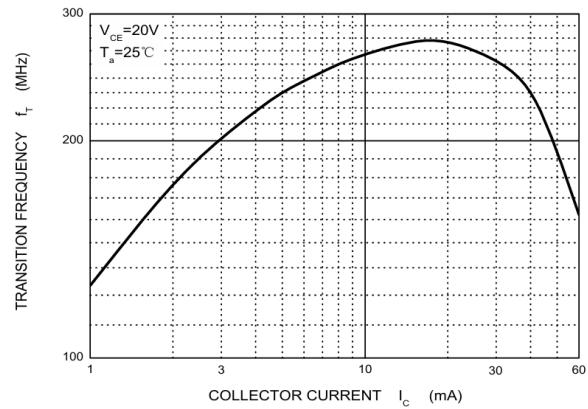
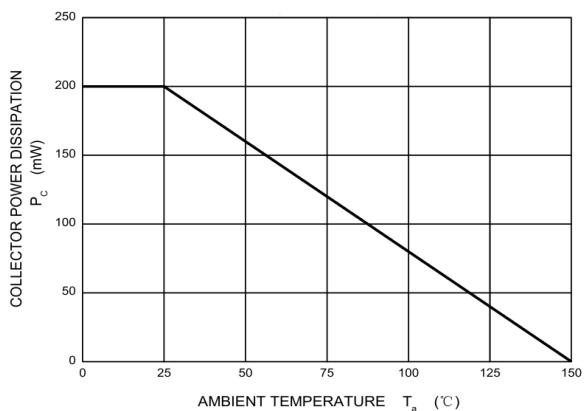


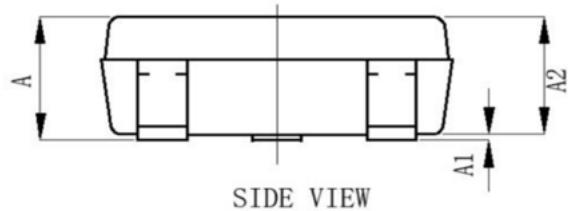
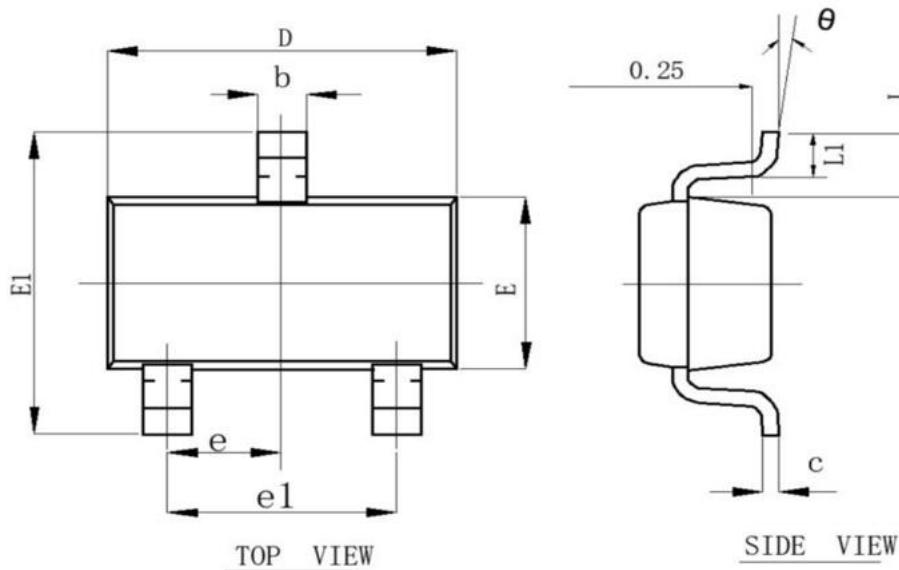
Fig 8. P_C vs. T_a





PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)



SYMBOL	MIN	MAX
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.00
E	1.200	1.400
E1	2.250	2.550
L	0.550	REF
θ	0°	8°
L1	0.300	0.500
e	0.950	TYP.
e1	1.800	2.000



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